

# LESD8D18CT5G ESD PROTECTION DIODE

## Discription

The LESD8D18CT5G is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space is at a premium.

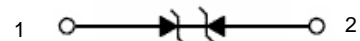
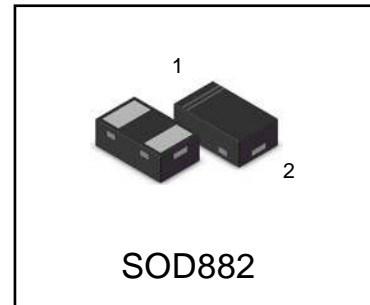
## Applications

- | Cellular phones audio
- | MP3 players
- | Digital cameras
- | Portable applications
- | mobile telephone

## Features

- | Low Leakage
- | Response Time is Typically < 1 ns
- | IEC61000-4-2 Level 4 ESD Protection
- | We declare that the material of product compliance with RoHS requirements and Halogen Free.

LESD8D18CT5G



## Ordering information

Device	Marking	Shipping
LESD8D18CT5G	8T	10000/Tape&Reel

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Air Contact Contact discharge		±30 ±30	kV kV
Total Power Dissipation on FR-5 Board (Note 1) @ T <sub>A</sub> =25°C	PD	200	mW
Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 to 150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

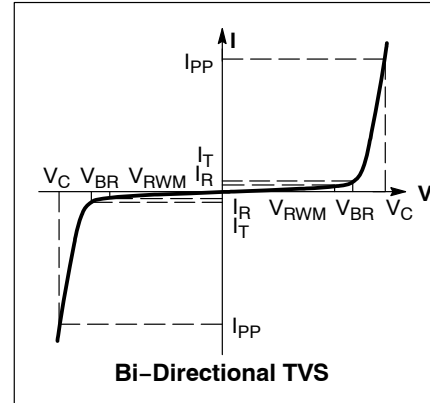
1. FR-5 = 1.0\*0.75\*0.62 in.

# LESD8D18CT5G

## ELECTRICAL CHARACTERISTICS

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$P_{pk}$	Peak Power Dissipation
C	Capacitance @ $V_R = 0$ and $f = 1.0$ MHz

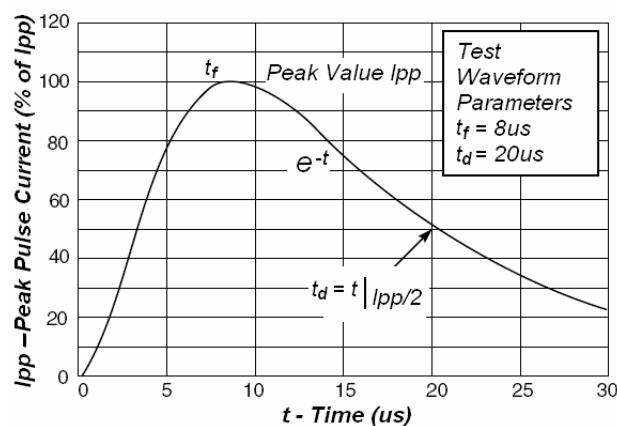


## ELECTRICAL CHARACTERISTICS

Device	$V_{RWM}$ (V)	$I_{R1}(\mu\text{A})$ @ $V_{RWM}$	$V_{BR}$ (V) @ $I_T$ (Note 2)		$I_T$	$V_C$ (V) @ $I_{PP} = 3$ A (Note 3)	$V_C$ (V) @ MAX $I_{PP}$ (Note 3)	$I_{PP}$ (A) (Note 3)	$P_{PK}$ (W) (Note 3)	C (pF)
	Max	Max	Min	Max	mA	Max	Max	Max	Max	Max
LESD8D18CT5G	18	0.3	19	23	1.0	27	29	4	116	45

Other voltage available upon request.

- $V_{BR}$  is measured with a pulse test current  $I_T$  at an ambient temperature of  $25^\circ\text{C}$
- Surge current waveform per Figure 1.



# LESD8D18CT5G

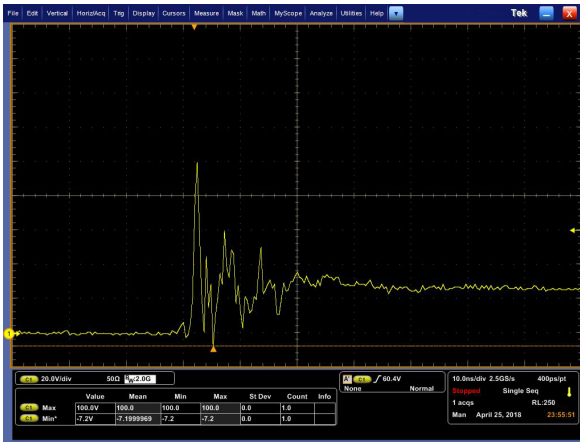


Figure 2. ESD Clamping Voltage Screenshot Positive 8 kV Contact per IEC61000-4-2

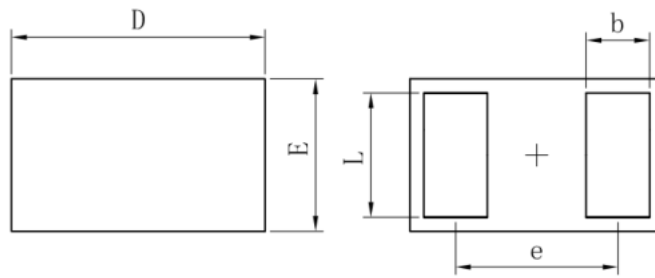


Figure 3. ESD Clamping Voltage Screenshot Negative 8 kV Contact per IEC61000-4-2

# LESD8D18CT5G

## OUTLINE AND DIMENSIONS

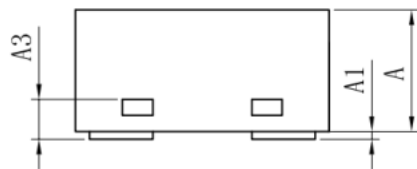
### SOD882



TOP VIEW

BOTTOM VIEW

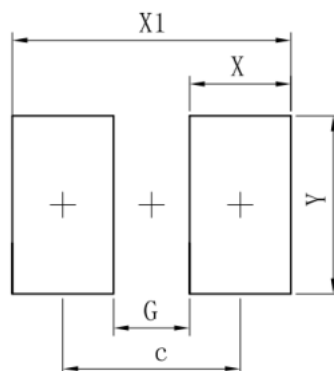
SOD882			
Dim	Min	Typ	Max
D	0.95	1.00	1.05
E	0.55	0.60	0.65
e	-	0.64	-
L	0.44	0.49	0.54
b	0.20	0.25	0.30
A	0.43	0.48	0.53
A1	0	-	0.05
A3	0.127REF.		
All Dimensions in mm			



SIDE VIEW

## SOLDERING FOOTPRINT

### SOD882



Dimensions	(mm)
c	0.70
G	0.30
X	0.40
X1	1.10
Y	0.70